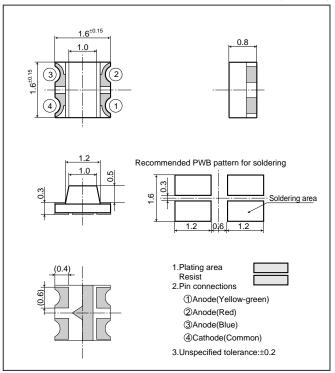
# LT1W67A(Under Development)

## 1616 Size, 0.8mm Thickness, Compact Full Color Leadless Chip LED Device

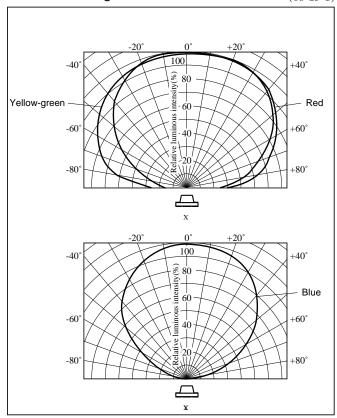
#### Outline Dimensions





#### **■** Radiation Diagram

(Ta=25°C)



#### ■ Absolute Maximum Ratings

 $(T_a=25^{\circ}C)$ 

Model No.	Radiation color	Radiation material	Power dissipation  P*1  (mW)	Forward current  IF  (mA)  Peak forward current  IFM*2  (mA)		Derating factor (mA/°C)  DC Pulse		Reverse voltage V <sub>R</sub> (V)	Operating temperature  Topr (°C)	Storage temperature $T_{stg}$ (°C)	Soldering temperature $T_{sol}^{*3}$ (°C)
LT1W67A	Blue	GaN on SiC	200	30	100	0.67	1.33	5	-30 to +85	-40 to +100	260
	Yellow-green	GaP	84	30	50	0.40	0.67	5	-30 to +85	-40 to +100	260
	Red	GaAsP on GaP	84	30	50	0.40	0.67	5	-30 to +85	-40 to +100	260

<sup>\*1</sup> The value is specified under the condition that either color is lightened separately.

When all diodes are lightened simultaneously, the power dissipation of each diode should be less than 30% of the value specified in this table.

### **■** Electro-optical Characteristics

 $(T_a=25^{\circ}C)$ 

Lens type	Model No.	Radiation color	Forward voltage V <sub>F</sub> (V)		Peak emission wavelength		Luminous intensity		Spectrum radiation bandwidth		Reverse current		Terminal capacitance		Page for
					$\lambda_p(nm)$	IF	Iv(mcd)	IF	$\Delta\lambda(nm)$	$\mathbf{I}_{\mathrm{F}}$	Ir(µA)	$V_R$	C <sub>t</sub> (pF)	0.07	characteristics
			TYP	MAX	TYP	(mA)	TYP	(mA)	TYP	(mA)	MAX	(V)	TYP	(MHz)	diagrams
Milky diffusion	LT1W67A	Blue	4.4	5.6	430	20	6.5	20	70	20	10	4	50	1	_
		Yellow-green	2.1	2.8	565	20	13.0	20	30	20	10	4	35	1	_
		Red	2.0	2.8	635	20	8.5	20	35	20	10	4	20	1	_

<sup>\*2</sup> Duty ratio=1/10, Pulse width=0.1ms

<sup>\*3</sup> For 3s or less at the temperature of hand soldering. Temperature of reflow soldering is shown on the below page.